

Rectifier Diode

Avalanche Diode

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$$\begin{aligned} V_{\text{RRM}} &= 800\text{-}1800 \text{ V} \\ I_{\text{F(RMS)}} &= 160 \text{ A} \\ I_{\text{E(AV)M}} &= 110 \text{ A} \end{aligned}$$

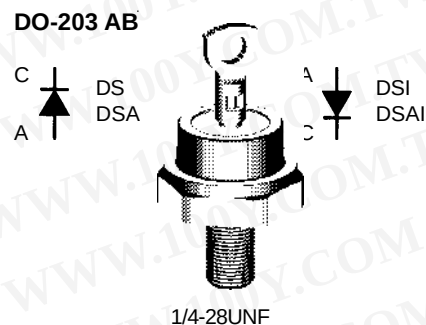
V_{RSM} V	$V_{(BR)min}$ ① V	V_{RRM} V	 Anode on stud	 Cathode on stud
900	-	800	DS 75-08B	DSI 75-08B
1300	-	1200	DS 75-12B	DSI 75-12B
1300	1300	1200	DSA 75-12B	DSAI 75-12B
1700	1760	1600	DSA 75-16B	DSAI 75-16B
1900	1950	1800	DSA 75-18B	DSAI 75-18B

① Only for Avalanche Diodes

Symbol	Test Conditions	Maximum Ratings	
$I_{F(RMS)}$	$T_{VJ} = T_{VJM}$	160	A
$I_{F(AV)M}$	$T_{case} = 100^{\circ}\text{C}; 180^{\circ} \text{ sine}$	110	A
P_{RSM}	DSA(I) types, $T_{VJ} = T_{VJM}, t_p = 10 \mu\text{s}$	20	kW
I_{FSM}	$T_{VJ} = 45^{\circ}\text{C};$	1400	A
	$V_R = 0$	1500	A
	$T_{VJ} = T_{VJM}$	1250	A
	$V_R = 0$	1310	A
I^2t	$T_{VJ} = 45^{\circ}\text{C}$	9800	A ² s
	$V_R = 0$	9450	A ² s
	$T_{VJ} = T_{VJM}$	7820	A ² s
	$V_R = 0$	7210	A ² s
T_{VJ}		-40...+180	$^{\circ}\text{C}$
T_{VJM}		180	$^{\circ}\text{C}$
T_{stg}		-40...+180	$^{\circ}\text{C}$
M_d	Mounting torque	2.4-4.5	Nm
		21-40	lb.in.
Weight		21	g

Symbol	Test Conditions	Characteristic Values	
I_R	$T_{VJ} = T_{VJM}; V_R = V_{RRM}$	$\leq$	6 mA
V_F	$I_F = 150 \text{ A}; T_{VJ} = 25^\circ\text{C}$	$\leq$	1.17 V
V_{T0}	For power-loss calculations only		0.75 V
r_T	$T_{VJ} = T_{VJM}$		2 mΩ
R_{thJC}	DC current		0.5 K/W
R_{thJH}	DC current		0.9 K/W
d_s	Creepage distance on surface		4.05 mm
d_a	Strike distance through air		3.9 mm
a	Max. allowable acceleration		100 m/s ²

Data according to IEC 60747
IXYS reserves the right to change limits, test conditions and dimensions



A = Anode C = Cathode

Features

- International standard package, JEDEC DO-203 AB (DO-5)
- Planar glassivated chips

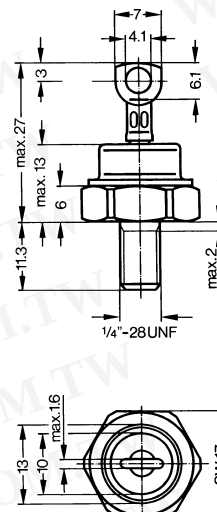
Applications

- High power rectifiers
- Field supply for DC motors
- Power supplies

Advantages

- Space and weight savings
- Simple mounting
- Improved temperature and power cycling
- Reduced protection circuits

Dimensions in mm (1 mm = 0.0394")



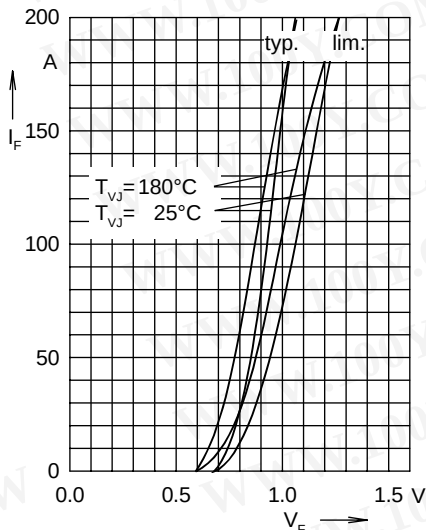


Fig. 1 Forward characteristics

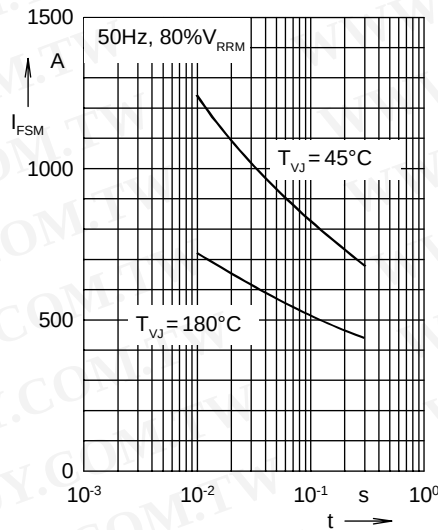


Fig. 2 Surge overload current
 I_{FSM} : crest value, t : duration

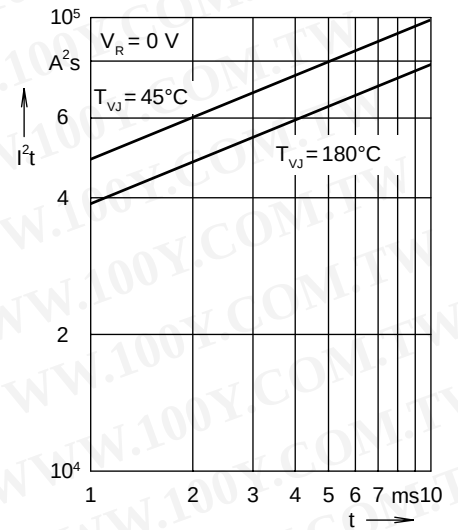


Fig. 3 I^2t versus time (1-10 ms)

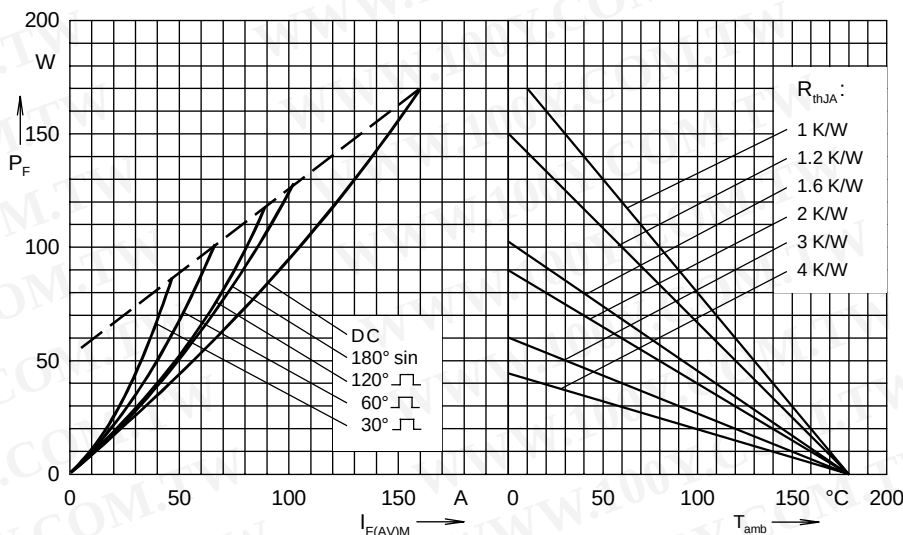


Fig. 4 Power dissipation versus forward current and ambient temperature

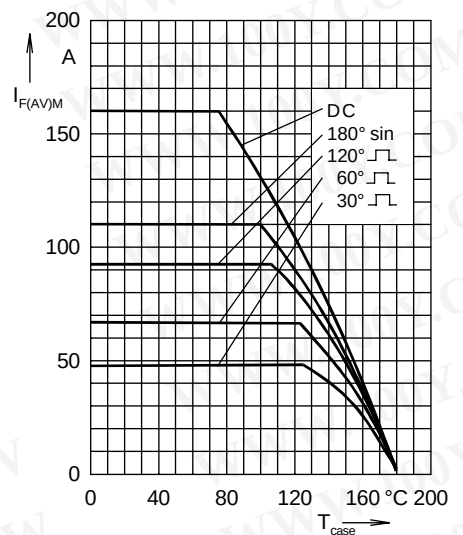


Fig. 5 Max. forward current at case temperature

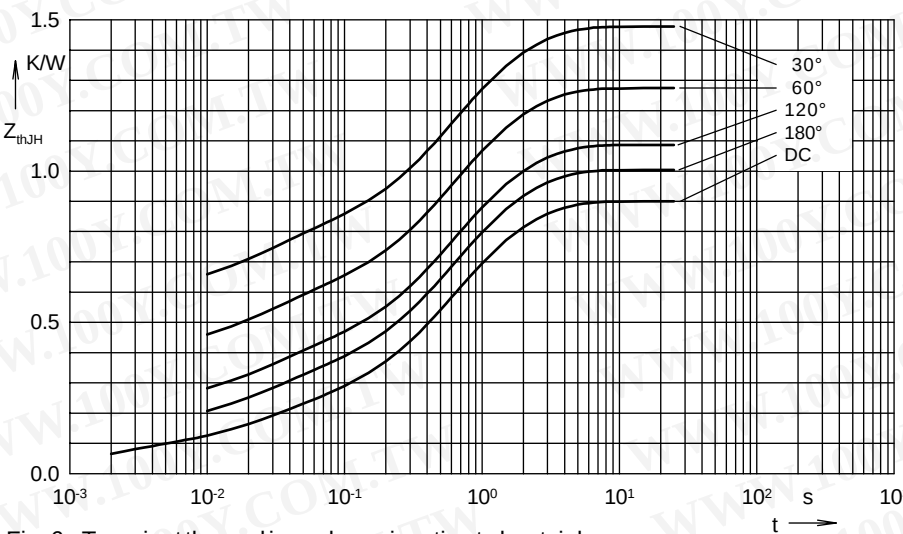


Fig. 6 Transient thermal impedance junction to heatsink

R_{thJH} for various conduction angles d :

d	R_{thJH} (K/W)
DC	0.900
180°	1.028
120°	1.085
60°	1.272
30°	1.476

Constants for Z_{thJH} calculation:

i	R_{thi} (K/W)	t_i (s)
1	0.0731	0.0015
2	0.1234	0.0237
3	0.4035	0.4838
4	0.3000	1.5